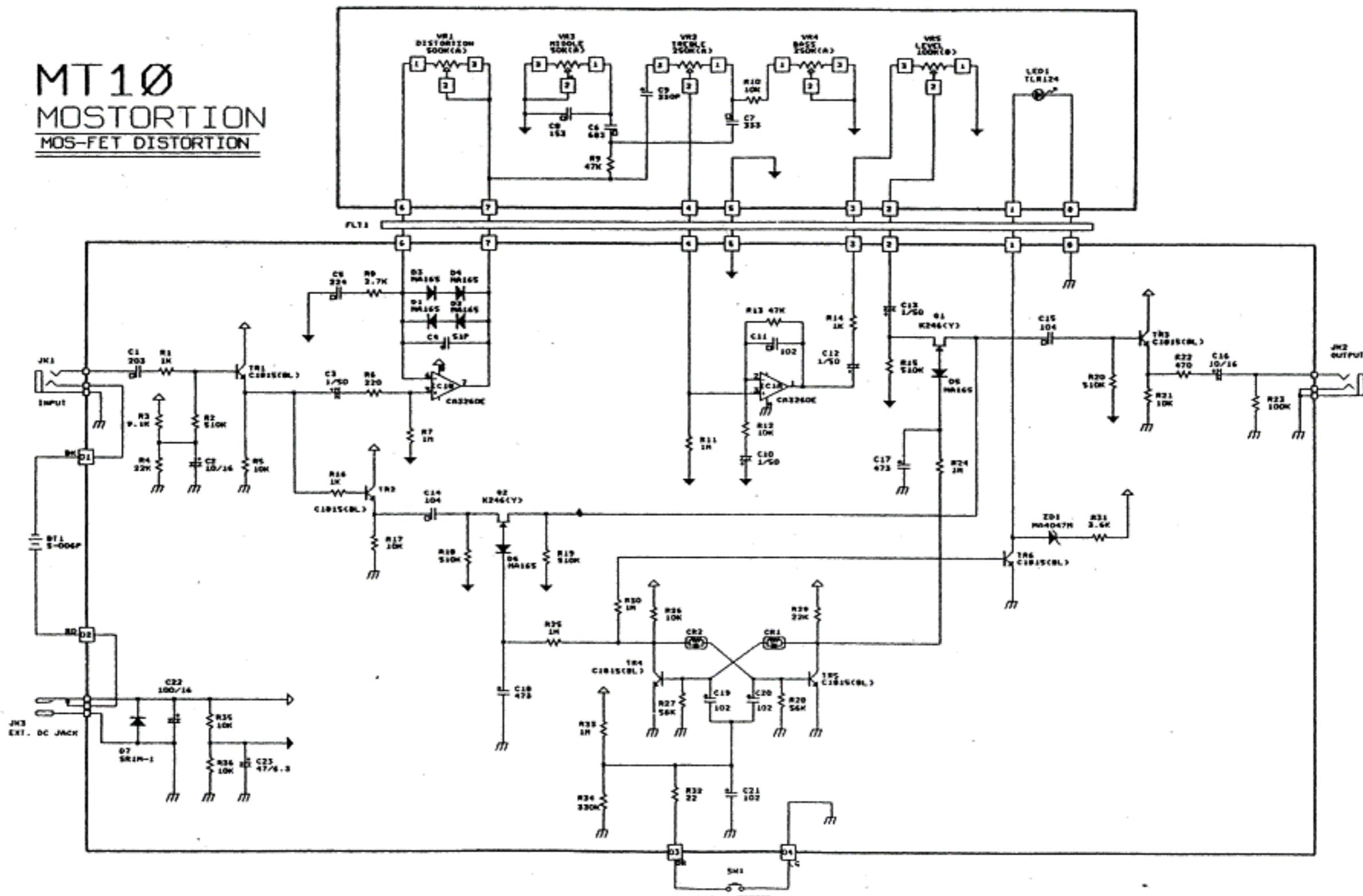


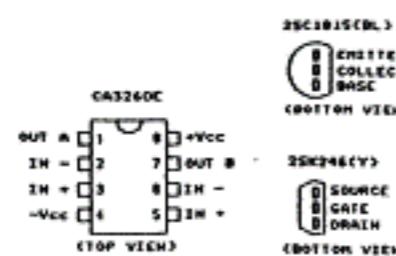
# MT10

## MOSTORTION

MOS-FET DISTORTION



EG. TR1 & LATE	
ZG 1	IC3260C
TR1&6	2SC1815(CBL)
Q1,2	2SK246CY3
Q1&6	IRL165



2SK246CY3  
 SOURCE  
 GATE  
 DRAIN  
 (TOP VIEW)  
 CATHODE  
 ANODE  
 (Emitter View)

IRF165  
 Emitter View  
 IRF165  
 Cathode  
 Anode  
 Emitter View

\*\* NOTES \*\*  
 A : CERAMIC capacitor;  
 B : FILM capacitor;  
 C : FILM capacitor above 50V rating;  
 D : POLAR capacitor;  
 E : POLAR capacitor;  
 F : TANTALUM capacitor;  
 G : all capacitors are ELECTROLYTIC capacitors unless otherwise specified;  
 H : Unless otherwise indicated,  
 I : Resistance in  $\Omega$ , K $\Omega$ , M $\Omega$ ,  
 J : Resistors, 1/4W or 1/8W +/- 5% rating;  
 K : Capacitance in pF, uF

\*\* CAUTION \*\*  
 This schematic diagram is a normal standard one.  
 The parts rating and/or schematic diagram will be  
 subject to change without notice.

Title	
MT10 MOSTORTION	
Issue Document Number	
C	
Date	Rev B, 1990 Sheet
REV	